

covering Electronic Components,
Assemblies, Related Materials and Processes

For rules and details of the IECQ visit www.iecq.org

Schedule of Scope to Certificate of Approval Independent Testing Laboratory

IECQ Certificate No.: IECQ-L JQAJP 13.0002
CB Certificate No.: JQAQ0002-001-T

Schedule Number: IECQ-L JQAJP 13.0002-S Rev No.: 4 Revision Date: 2016/01/22 Page 1 of 8

TESTD PARTS

Fixed capacitor, Fixed resistor, Potentiometer, Varistor, Thermistor, Connector, Relay, Switch, Printed circuit board, Semiconductor Devices, Semiconductor Integrated Circuit and Optical Component

ENVIRONMENTAL TEST

	LS1
IEC 60068-2-1:2013	Cold
IEC 60068-2-2:2007	Dry heat
IEC 60068-2-11:1981	Salt mist
IEC 60068-2-14:2009	Change of temperature
IEC 60068-2-20:2008	Test methods for solderability and resistance
	to soldering heat of devices with leads
IEC 60068-2-30:2005	Damp heat, cyclic (12+12-hour cycle)
IEC 60068-2-38:2009	Composite temperature/humidity cyclic test
JIS C 60068-2-42:1993	Sulphur dioxide test for contacts and connections
JIS C 60068-2-43:1993	Hydrogen sulphide test for contacts and connections
IEC 60068-2-45:1980	Immersion in cleaning solvents
IEC 60068-2-52:1996	Salt mist, cyclic (sodium chloride solution)
IEC 60068-2-54:2006	Soldering. Solderability testing by
	the wetting balance method
IEC 60068-2-58:2004	Test methods for solderability, resistance to dissolution of
	metallization and to soldering heat of SMD
IEC 60068-2-60:1995	Flowing mixed gas corrosion test
IEC 60068-2-66:1994	Damp heat, steady state (unsaturated pressurized vapour)
IEC 60068-2-78:2012	Damp heat, steady state
JIS K 6259-1:2015	Rubber, vulcanized or thermoplastic-
	Determination of ozone resistance-
	Part 1: Static and dynamic strain testing
MIL STD 202G	Test method standard electronic and electrical component parts
MIL STD 883J	Test method standard microcircuts





covering Electronic Components, Assemblies, Related Materials and Processes

For rules and details of the IECQ visit www.iecg.org

Schedule of Scope to Certificate of Approval

Independent Testing Laboratory IECQ Certificate No.: IECQ-L JQAJP 13.0002

CB Certificate No.: JQAQ0002-001-T

Schedule Number: IECQ-L JQAJP 13.0002-S Revision Date: 2016/01/22 Rev No.: 4 Page 2 of 8

MECHANICAL TEST

Vibration (sinusoidal) IEC 60068-2-6:2007

IEC 60068-2-21:2006 Robustness of terminations and

integral mounting devices

IEC 60068-2-27:2008

IEC 60068-2-31:2008 Rough handling shocks, primarily for

equipment-type specimens

IEC 60068-2-53:2010 Tests and Guidance: Combined climatic (temperature/humidity)

and dynamic (vibration/shock) tests

STRESS TEST

JEITA ED-4701/302:2013

Environmental and endurance test methods for semiconductor devices

(Stress test I-2)

Test method 304A Human body model electrostatic discharge (HBM/ESD)

Test method 305C Charged device model electrostatic discharge (CDM/ESD)

Test method 306B Latch-up

JEITA ED-4701/600:2013

Environmental and endurance test methods for semiconductor devices

(Specific test for discrete semiconductors)

Test method 601 Power cycling test (Molding type)

Test method 602 Power cycling test (Non-molding type/short time)

Test method 603 Power cycling test (Non-molding type/long time)

This approval and any schedule(s) may only be reproduced in full. This approval is not transferable and remains the property of the issuing body. The Status and authenticity of this approval and any schedule(s) may be verified by visiting the



This schedule is only valid in conjunction with the referenced Certificate of Approval

Official IECQ Website. www.iecq.org



covering Electronic Components, Assemblies, Related Materials and Processes

For rules and details of the IECQ visit www.iecq.org

Schedule of Scope to Certificate of Approval

Independent Testing Laboratory

IECQ Certificate No.: IECQ-L JQAJP 13.0002
CB Certificate No.: JQAQ0002-001-T

Schedule Number: IECQ-L JQAJP 13.0002-S Rev No.: 4 Revision Date: 2016/01/22 Page 3 of 8

LED OPTICAL CHARACTERISTIC TEST

JIS C 7801:2009 Measuring methods of lamps for general lighting JIS C 8152-1:2012 Photometry of white light emitting diode for

general lighting — Part 1: LED packages

JIS C 8152-2:2012 Photometry of white light emitting diode for general lighting

- Part 2: LED modules and LED light engines

JIS C 8105-5:2011 Luminaires — Part 5: Gonio-photometric method

OTHER TEST

Failure Analysis, Construction Analysis, Elemental Analysis, Thermal Analysis and Internal Gas Analysis of Electronic component, including Electrical Analysis, NDE (Non-destructive Engineering), Physical Analysis, Chemical Analysis and Sample Preparation (Decap, X-section, etc),





covering Electronic Components, Assemblies, Related Materials and Processes

For rules and details of the IECQ visit www.iecq.org

Schedule of Scope to Certificate of Approval

Independent Testing Laboratory

IECQ Certificate No.: IECQ-L JQAJP 13.0002
CB Certificate No.: JQAQ0002-001-T

Schedule Number: IECQ-L JQAJP 13.0002-S Rev No.: 4 Revision Date: 2016/01/22

Page 4 of 8

MEASUREMENT RANGE

Passive component

Type / Part name	Measurable property value	Measuring range	
	(1)Voltage endurance (DC)	: AC,DC 0 ~ 5kV	
	(2)Insulation resistance	$: 5 \times 10^5 \Omega \sim 10^{14} \Omega$	
	(3)leakage current	$1 \times 10^{-3} \sim 10 \text{ A}^{-11}$	
Fixed capacitor	(4)Capacitance	$: 18pF \sim 1F^*$	
	(5)Dielectric loss tangent(D factor)	: 10* min	
•	(6)Impedanc	: $1\Omega \sim 10^* M\Omega$	
	(7)Temperature properties and		
	gap of the capacitance.	: Temperature range -40° C $\sim +150^{\circ}$ C	
	Attention: * The mark varie	Attention: * The mark varies according to measurement frequency.	
	(1)Resistance value	$1 \Omega \sim 100 \Omega$	
	(2)Resistance temperature properties and	d	
Fixed resistor	gap of the resistance level.	:Temperature range -55° C $\sim +150^{\circ}$ C	
Fixed resistor	(3) Voltage factor	:±0.02%/V	
	(4)Insulation resistance	$: 5 \times 10^5 \Omega \sim 2 \times 0^{14} \Omega$	
	(5) Voltage endurance	: AC,DC $0 \sim 5$ kV	
	(1)Resistance value	: $1 \Omega \sim 100 \text{M}\Omega$	
	(2)Mutual deviations	: ±3%	
	(3)Resistance temperature properties and	d	
Variable resistor	gap of the resistance level.	:Temperature range $-40^{\circ}\text{C} \sim +150^{\circ}\text{C}$	
*potentiometer	(4)Insulation resistance	$: 5 \times 10^5 \Omega \sim 10^{14} \Omega$	
	(5) Voltage endurance	: AC,DC $0 \sim 5$ kV	
	(6)Rotational noise	:Noise voltage 1mV	
	(7)Intensive contact resistance	:1 mΩ	
Varistor	Voltage at reference current	:1500V(1mA min)	
Themsister	(1)resistance value	$:1\Omega \sim 1000 \text{k}\Omega$	
Thermistor	(2)The thermistor fixed number	:Temperature range -50° C $\sim +300^{\circ}$ C	





covering Electronic Components, Assemblies, Related Materials and Processes

For rules and details of the IECQ visit www.iecq.org

Schedule of Scope to Certificate of Approval Independent Testing Laboratory

IECQ Certificate No.: IECQ-L JQAJP 13.0002
CB Certificate No.: JQAQ0002-001-T

Schedule Number: IECQ-L JQAJP 13.0002-S Rev No.: 4 Revision Date: 2016/01/22 Page 5 of 8

MEASUREMENT RANGE

Active component part [Individual semiconductor part]

Type / Part name	Measurable property value M	leasuring range
	(2)Collector-emitter breakdown voltage	
	(3)Emitter base breakdown voltage	:100V min
Transistor	(4)Collector base interception electric curr	
*Bipolar	(5)Collector emitter interception electric of	
	(6)Emitter base interception electric curre	
	(7)The collector emitter saturation voltage	
	(8)DC current gain	$:25 \sim 25,000 (I_C < 17A)$
	(1)Gate source breakdown voltage	$:1V \sim 1.5kV$
Transistor	(2)Gate leak electric current	$:1pA \sim 100mA$
	(3)Drain current	$:1nA \sim 1A$
*Field effect form	(4)The gate cut-off voltage	:~100V
	(5)The drain source saturation voltage	:7V min $(I_D < 17A)$
Diode	(1)Forward voltage	:7V min $(I_F < 17A)$
*Small signal	(2)Reverse current	$:1$ na ~ 100 mA ($V_R < 100$ V)
*I rectify a small electric current	(3)Breakdown voltage	$:1V \sim 1.5kV$
*Constant voltage	(4)Zener voltage	:100V min
*Small electric current switching	(5)Dynamic resistance	:50 Ω max
	(6)Temperature coefficient	:Temperature range -55° C $\sim +150^{\circ}$ C
Thyristor	(1)Off electric current	$:1 \text{mA} (V_L < 1 \text{kV})$
*3 reverse-blocking terminals	(2)Reverse current	$:1na \sim 1mA (V_L < 1kV)$
*Small electric current	(3)ON-state voltage	$:7V (I_{TM} < 10A)$
	(4)Gate trigger	:1000V min
	(5)Holding current	$:10A(V_{TM} < 7V)$





covering Electronic Components,
Assemblies, Related Materials and Processes

For rules and details of the IECQ visit www.iecq.org

Schedule of Scope to Certificate of Approval Independent Testing Laboratory

IECQ Certificate No.: IECQ-L JQAJP 13.0002
CB Certificate No.: JQAQ0002-001-T

Schedule Number: IECQ-L JQAJP 13.0002-S Rev No.: 4 Revision Date: 2016/01/22 Page 6 of 8

MEASUREMENT RANGE

Active component part Semicondctor Devices [Integrated circuit]

Type / Part name	Measurable property value Mea	suring range
•	(1)The high-level output voltage	:±30V
	(2)The low-level output voltage	:±30V
	(3)The input clamp voltage	:±30V
TTL IC	(4)High-level input electric current	:±300mA
	(5)Low-level input electric current	:±300mA
	(6)Output short circuit current	:±300mA
	(7)High-level power supply electric current	:±300mA
	(8)Low-level power supply electric current	:±300mA
	(1)The high-level output voltage	:±30V
	(2)The low-level output voltage	:±30V
	(3)The high-level input voltage	:±20V
CMOS IC	(4)Low-level input electric current	:±20V
CIVIOS IC	(5)High-level output electric current	:±300mA
	(6)Low-level output electric current	:±300mA
	(7)Static consumption electric current	:±300mA
	(8)Input current	:±300mA
	(1)Input-offset voltage	$:\!10\mu V\sim 128mV$
	(2)Input offset current	:20pA ~ 16μA
	(3)Input bias current	:20pA ~ 16μA
A = 1 = = = 1 = 1 = 1 = 1	(4)Open loop voltage gain	$:0.1V/mV \sim 1.2V/\mu V$
Analog semiconductor integrated circuit *Monolithic op-amp	(5)The max power voltage	:10mV ~ 50V
	(6)Power consumption	:5mW ~ 6.4W
	(7)Common mode rejection ratio	:38 ~ 116dB
	(8)Supply voltage rejection ratio	:38 ~ 116dB
	(9)Aspect input voltage range	$:100 \text{mV} \sim 25 \text{V}$
	(10)Slew rate	$: 0.1 \sim 125 V/\mu S$





covering Electronic Components, Assemblies, Related Materials and Processes

For rules and details of the IECQ visit www.iecq.org

Schedule of Scope to Certificate of Approval

Independent Testing Laboratory IECQ Certificate No.: IECQ-L JQAJP 13.0002

CB Certificate No.: JQAQ0002-001-T

Schedule Number: IECQ-L JQAJP 13.0002-S Rev No.: 4 Revision Date: 2016/01/22 Page 7 of 8

MEASUREMENT RANGE

Mechanical device

Type / Part name	Measurable property value	Measuring range
	(1)Insulationresistanc	$:5\times 10^5 \Omega \sim 2\times 10^{14} \Omega$
Connector (Electronic equipment use)	(2)Withstand voltage	:AC,DC $0 \sim 5 \text{kV}$
	(3)Contact resistance under low voltage,	
	the low electric current	$:1 \text{m}\Omega \sim 100\Omega$
	(4)Chattering of the contact.	:1μsec max
	(1)Withstand voltage	:AC,DC $0 \sim 5 \text{kV}$
	(2)Insulation resistance	$:5\times 10^5 \Omega \sim 2\times 10^{14} \Omega$
	(3)Direct current resistance of the coil	$:1\Omega \sim 10 \mathrm{k}\Omega$
	(4)Contact resistance	$:1 \mathrm{m}\Omega \sim 100 \Omega$
Relay	(5)Operating voltage	:1V max
(Small form for control)	(6)Must-release voltage	:1V max
	(7)Operation time	:1msec max
	(8)Recovery time	:1msec max
	(9)Bounces of the point of contact	:1µsec max
	(10)Chattering of the point of contact	:1µsec max
	(1)Contact resistance	$:1 \mathrm{m}\Omega \sim 100 \Omega$
Switch	(2)Insulation resistance	$:5\times10^{5}\Omega\sim2\times10^{14}\Omega$
(Electronic equipment use)	(3)Withstand voltage	: AC,DC $0 \sim 5$ kV
	(4)Electrostatic capacity	$:18pF \sim 1F$
	(5) Change of the contact resistance	$:1\mathrm{m}\Omega$ max
	(1)Resistance of the plating part of	
Printed circuit board	the conductor and through hall p	eart. : $1 \text{m}\Omega \sim 1000\Omega$
Frinted circuit board	(2)Withstand voltage	: AC,DC $0 \sim 5 \text{kV}$
	(3)Insulation resistance	$: 5 \times 10^5 \Omega \sim 10^{14} \Omega$





covering Electronic Components,
Assemblies, Related Materials and Processes

For rules and details of the IECQ visit www.iecq.org

Schedule of Scope to Certificate of Approval Independent Testing Laboratory

IECQ Certificate No.: IECQ-L JQAJP 13.0002
CB Certificate No.: JQAQ0002-001-T

Schedule Number: IECQ-L JQAJP 13.0002-S Rev No.: 4 Revision Date: 2016/01/22 Page 8 of 8

MEASUREMENT RANGE

Optical component

Type / Part name	Measurable property value	Measuring range		
Luminescent diode (It is for indication.)	(1)Forward voltage	:7V min		
	(2)Reverse current	:1mA min		
	(3)Luminous intensity(Relative v	alue) :		
	1.Integrating sphere			
	(1)Total luminous flux[lm]	:Measurable wavelength range		
		$350 \text{nm} \sim 1000 \text{nm}$		
		:F[lm] :min $32lm \sim In sunshine$		
	(2)Color temperature[K]	;		
	(3)Chromaticity coordinate	;		
	(4)The number of the color re	endering evaluations :Ra,R1 ~ R14		
	2.The light distribution measuren	nent.		
LED	(1)Light distribution curve	:Measurable wavelength range		
(It is for illumination.)		360nm ~ 830nm		
		:Photometric distance 2m ~ 12m,		
	(2)Light intensity(Reference)	:Photometric distance Luminous intensity		
		:2.0m: 9 ~ 3,680,000[cd]		
		$:3.0m:$ $20 \sim 8,200,000[cd]$		
		$83 \sim 33,000,000$ [cd]		
		:12m : $330 \sim 132,000,000$ [cd]		
	(3)Color temperature	:		
	(4)Chromaticity coordinate	[
	(5) The number of the color re	(5) The number of the color rendering evaluations: Ra,R1 ~ R14		

